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TOTAL

=> file reg

COST IN U.S. DOLLARS SINCE FILE TOTAL ENTRY SESSION 28.35 31.83

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=>
Uploading C:\Program Files\Stnexp\Queries\10732812-BROADRCE.str

L2 STRUCTURE UPLOADED

=> d 12 L2 HAS NO ANSWERS L2 STR

G1 Me, Et, Ph

Structure attributes must be viewed using STN Express query preparation.

=> s 11

22020136 1

2086 DIETHYLPHOSPHINO

24293915 2

0 TRIETHOXYSULYLETHANE

L3

0 1-DIETHYLPHOSPHINO-2-TRIETHOXYSULYLETHANE

(1 (W) DIETHYLPHOSPHINO (W) 2 (W) TRIETHOXYSULYLETHANE)

=> s 12

SAMPLE SEARCH INITIATED 18:21:49 FILE 'REGISTRY'

SAMPLE SCREEN SEARCH COMPLETED - 53 TO ITERATE

100.0% PROCESSED 53 ITERATIONS

11 ANSWERS

SEARCH TIME: 00.00.01

FULL FILE PROJECTIONS: ONLINE **COMPLETE**

BATCH **COMPLETE**

PROJECTED ITERATIONS: 624 TO 1496

PROJECTED ANSWERS: 22 TO 418

L4 11 SEA SSS SAM L2

=> s 12 full

FULL SEARCH INITIATED 18:21:54 FILE 'REGISTRY'

FULL SCREEN SEARCH COMPLETED - 861 TO ITERATE

100.0% PROCESSED 861 ITERATIONS . 178 ANSWERS

SEARCH TIME: 00.00.01

L5 178 SEA SSS FUL L2

=> file caplus

COST IN U.S. DOLLARS SINCE FILE TOTAL

FULL ESTIMATED COST ENTRY SESSION 192.35 224.18

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=> s 15

L6 242 L5

=> s 16 not py > 2003 4901458 PY > 2003

L7 214 L6 NOT PY > 2003

=> s 17 and copper

959550 COPPER

L8 7 L7 AND COPPER

=> d 18 ibib abs hitstr 1-

YOU HAVE REQUESTED DATA FROM 7 ANSWERS - CONTINUE? Y/(N):y

L8 ANSWER 1 OF 7 CAPLUS COPYRIGHT 2007 ACS on STN

ACCESSION NUMBER:

2003:997121 CAPLUS

DOCUMENT NUMBER:

140:137074

TITLE:

Robust self-assembled monolayer as diffusion barrier

for copper metalization

AUTHOR (S):

Mikami, Noboru; Hata, Nobuhiro; Kikkawa, Takamaro;

Machida, Hideaki

CORPORATE SOURCE:

Association of Super-Advanced Electronics Technology (ASET), MIRAI, Tsukuba, Ibaraki, 305-8569, Japan

SOURCE:

Applied Physics Letters (2003), 83(25), 5181-5183

CODEN: APPLAB; ISSN: 0003-6951

PUBLISHER:

American Institute of Physics

DOCUMENT TYPE:

Journal

LANGUAGE:

English

AB Excellent results on copper (Cu) diffusion barrier characteristics of a self-assembled monolayer (SAM) of 2-(diphenylphosphino)ethyltriethoxy-silane are reported. The thickness and roughness of the SAM were determined by grazing incidence x-ray reflectometry as 1.7 and 0.3 nm, resp. To evaluate Cu diffusion barrier performance of the SAM, Cu/SiO2/Si and Cu/SAM/SiO2/Si MOS capacitors were prepared to measure their lifetimes under the 2 MV/cm elec. bias at 498-548 K. The mean times to failure obtained from the Weibull plots of time to failures were 33.6, 9.24, 4.57, and 2.03 h at 498, 523, 533 and 548 K, resp. These values show that the barrier characteristic of the SAM of 1.7 nm in thickness is comparable to that of phys.-vapor-deposited Ta film of 20 nm in thickness. The estimated lifetime of the SAM barrier at the device operation temperature of 392 K is longer than 10 yr.

IT 18586-39-5, 2-(Diphenylphosphino)ethyltriethoxysilane

RL: TEM (Technical or engineered material use); USES (Uses)

(monolayers; robust self-assembled monolayer as diffusion barrier for copper metalization)

RN 18586-39-5 CAPLUS

CN Phosphine, diphenyl[2-(triethoxysilyl)ethyl]- (CA INDEX NAME)

$$\begin{array}{c} \text{OEt} \\ | \\ \text{EtO-Si-CH}_2\text{-CH}_2\text{-PPh}_2 \\ | \\ \text{OEt} \end{array}$$

REFERENCE COUNT: 6 THERE ARE 6 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L8 ANSWER 2 OF 7 CAPLUS COPYRIGHT 2007 ACS on STN

ACCESSION NUMBER: 1997:744563 CAPLUS

DOCUMENT NUMBER: 128:25955

TITLE: Formation of Crystalline Nanoclusters of Ag, Cu, Os,

Pd, Pt, Re, or Ru in a Silica Xerogel Matrix from

Single-Source Molecular Precursors

AUTHOR(S): Carpenter, Joseph P.; Lukehart, C. M.; Milne, Stephen

B.; Henderson, D. O.; Mu, R.; Stock, S. R.

CORPORATE SOURCE: Department of Chemistry, Vanderbilt University,

Nashville, TN, 37235, USA

SOURCE: Chemistry of Materials (1997), 9(12), 3164-3170

CODEN: CMATEX; ISSN: 0897-4756

PUBLISHER: American Chemical Society

DOCUMENT TYPE: Journal LANGUAGE: English

AB Metal complexes containing bifunctional ligands which possess alkoxysilyl functional groups have been prepared for seven metals of the first, second, or third transition metal series. Incorporation of these single-source precursors into silica xerogel matrixes using sol-gel chemical affords molecularly doped xerogels. Subsequent thermal treatment of these doped xerogels under reducing or oxidizing-then-reducing conditions affords nanoclusters of Ag, Cu, Os, Pd, Pt, Re, or Ru which are highly dispersed throughout the bulk of the xerogel matrix. Characterization of these nanocomposite materials by TEM, EDS, XRD, and electron diffraction indicates that the metal nanoclusters are highly crystalline A visible spectrum of the silver nanocomposite shows the expected surface plasmon resonance near 415 nm.

IT 199395-67-0P 199395-68-1P 199395-69-2P

199395-70-5P 199395-72-7P

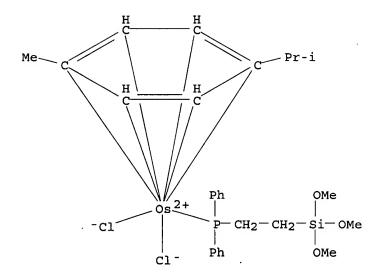
RL: PEP (Physical, engineering or chemical process); SPN (Synthetic preparation); PREP (Preparation); PROC (Process)

(mol. precursor; formation of crystalline nanoclusters of transition metals in a silica xerogel matrix from single-source mol. precursors)

RN 199395-67-0 CAPLUS

RN 199395-68-1 CAPLUS

CN Osmium, dichloro[diphenyl[2-(trimethoxysilyl)ethyl]phosphineκP][(1,2,3,4,5,6-η)-1-methyl-4-(1-methylethyl)benzene]- (9CI)
(CA INDEX NAME)



RN 199395-69-2 CAPLUS
CN Palladium, dibromobis[diethyl[2-(triethoxysilyl)ethyl]phosphine-κP], (SP-4-1)- (9CI) (CA INDEX NAME)

$$\begin{array}{c|c} & \text{OEt} \\ & | \\ & | \\ \text{CH}_2-\text{CH}_2-\text{Si-OEt} \\ & | \\ \text{Et-P-Et} & \text{OEt} \\ \\ \hline -\text{Br-Pd}_2+\text{Br-OEt} \\ & | \\ \text{Et-P-CH}_2-\text{CH}_2-\text{Si-OEt} \\ & | \\ \text{Et} & \text{OEt} \\ \end{array}$$

RN 199395-70-5 CAPLUS
CN Platinum, dichlorobis[diphenyl[2-(trimethoxysilyl)ethyl]phosphineκP]-, (SP-4-1)- (9CI) (CA INDEX NAME)

RN 199395-72-7 CAPLUS

CN Rhenium(1+), pentacarbonyl[diphenyl[2-(trimethoxysilyl)ethyl]phosphine- κ P]-, (OC-6-22)-, tetrafluoroborate(1-) (9CI) (CA INDEX NAME)

CM 1

CRN 199395-71-6 CMF C22 H23 O8 P Re Si

CCI CCS

CM 2

CRN 14874-70-5

CMF B F4 CCI CCS

REFERENCE COUNT: 64 THERE ARE 64 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

ANSWER 3 OF 7 CAPLUS COPYRIGHT 2007 ACS on STN

ACCESSION NUMBER:

1995:769932 CAPLUS

DOCUMENT NUMBER:

123:163290

TITLE:

Antimicrobial inorganic powders with phosphonium

derivatives for industrial uses

INVENTOR(S):

Takatsu, Shozo; Iijima, Toshio; Hashimoto, Kazuyoshi; Inaba, Yoshiko; Shimura, Seiji

PATENT ASSIGNEE(S):

Nippon Chemical Ind, Japan

SOURCE: Jpn. Kokai Tokkyo Koho, 7 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 07165518	Α	19950627	JP 1993-342335	19931214
PRIORITY APPLN. INFO.:			JP 1993-342335	19931214
*				

OTHER SOURCE(S): MARPAT 123:163290 An antimicrobial composition is prepared by coating inorg. powder with organosilicon phosphonium salts (R1)3SiR2P+(R3)(R5)R4·X- where R1 = alkoxy, halo, acyl, one of 3 R1 may be OH; R2 = C1-6 alkylene; R3, R4, R5 = H, C1-20 alkyl, aryl, aralkyl, etc.; X = anion. The powder is chemical stable, resistant to heat, and effective against a wide spectrum of microorganisms. The inorg. powders include oxides, hydroxides, silicates, aluminosilicates, phosphates, polyphosphates, borates, sulfates, carbonates, metallic acid salts of Mg, Ca, Ba, Sr, Zn, Cu, Mn, Ni, Al, Fe, Cr, Ti. Si, and Zr.

IT 167221-68-3

RL: BAC (Biological activity or effector, except adverse); BSU (Biological

study, unclassified); BIOL (Biological study) (inorg. powders with antimicrobial phosphonium metal derivs. for industrial uses)

RN

167221-68-3 CAPLUS Phosphonium, dimethyloctadecyl[3-(trimethoxysilyl)propyl]-, chloride (9CI) CN (CA INDEX NAME)

MeO-Si-(CH₂)₃-
$$\frac{p}{p}$$
+(CH₂)₁₇-Me
OMe Me

● Cl -

ANSWER 4 OF 7 CAPLUS COPYRIGHT 2007 ACS on STN

ACCESSION NUMBER: 1995:559767 CAPLUS

DOCUMENT NUMBER: 122:304513

TITLE: Metallic foil with adhesion-promoting layer INVENTOR(S): Poutasse, Charles A., III; Kovacs, Andrea M.

PATENT ASSIGNEE(S): Gould Electronics Inc., USA Eur. Pat. Appl., 23 pp. SOURCE:

CODEN: EPXXDW

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
EP 637902	A1	19950208	EP 1994-305740	19940803
EP 637902	B1	19990331		
R: AT, BE, CH,	DE, DK	, ES, FR, GB	, GR, IE, IT, LI,	LU, MC, NL, PT, SE
AT 178451	${f T}$	19990415	AT 1994-305740	19940803
JP 07170064	Α	19950704	JP 1994-185028	19940805
CN 1106977	A	19950816	CN 1994-115038	19940805
PRIORITY APPLN. INFO.:			US 1993-103075	A 19930806
OTHER SOURCE(S):	MARPAT	122:304513		

This invention relates to a metallic foil, especially for printed-circuit boards, with an adhesion-promoting layer overlying ≥1 side of the foil, the adhesion-promoting layer comprising ≥1 silane coupling agent, the base surface of the foil underlying the adhesion-promoting layer being characterized by the absence of added surface roughening, the absence of Cr, and the absence of a layer of Zn or Cr adhered to the base surface.

IT 18586-39-5, 2-(Diphenylphosphino) ethyl triethoxy silane RL: DEV (Device component use); NUU (Other use, unclassified); USES (Uses) (metallic foil with adhesion-promoting layer containing)

RN 18586-39-5 CAPLUS

CN Phosphine, diphenyl[2-(triethoxysilyl)ethyl]- (CA INDEX NAME)

$$\begin{array}{c} \text{OEt} \\ | \\ \text{Eto-} \sin \text{CH}_2 - \text{CH}_2 - \text{PPh}_2 \\ | \\ \text{OEt} \end{array}$$

L8 ANSWER 5 OF 7 CAPLUS COPYRIGHT 2007 ACS on STN

ACCESSION NUMBER: 1994:56153 CAPLUS

DOCUMENT NUMBER: 120:56153

TITLE: Silane coupling agents for metalization of polymeric

substrates

INVENTOR(S): Swei, Gwo; Kristal, Kenneth W.

PATENT ASSIGNEE(S): Rogers Corp., USA

SOURCE: U.S., 7 pp.
CODEN: USXXAM

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
	170 522267		10020002	770 1000 F000FF	10000500
	US 5233067	A	19930803	US 1990-522375	19900508
PR.	IORITY APPLN. INFO.:			US 1990-522375	19900508
AB				contacting the surface	
				coupling agent and the	
٠.				t-extruded TE-97645 su	
	etched, treated s	successive	ly with CH2	::CHSi(OMe)3 (I) and HS	S(CH2)3Si(OMe)3
	(II), dried, bake	ed, and co	ated electr	olessly with Cu to give	ve a sample
	showing peel stre	ength 13-1	.5 lb/in and	l no significant reduct	tion after thermal
	aging, compared w	with 7 and	l significan	it reduction, resp., fo	or a similar sample
	without I and II.				-
IT	151535-59-0 15153	5-61-4		•	
	RI: USES (Uses)				

RL: USES (Uses)

(coupling agent, for polymer metalization)

RN 151535-59-0 CAPLUS

CN Phosphine, [3-{1,1-diethoxy-3,3-dimethoxy-3-[3-(oxiranylmethoxy)propyl]disiloxanyl]propyl]diphenyl- (9CI)

(oxiranylmethoxy)propyl]disiloxanyl]propyl]diphenyl- (9CI) (CA INDEX NAME)

OMe OET
$$CH_2-O-(CH_2)_3-Si-O-Si-(CH_2)_3-PPh_2$$
OMe OET

RN 151535-61-4 CAPLUS

CN Phosphine, [3-[1,1,3,3-tetraethoxy-3-(3-isocyanatopropyl)disiloxanyl]propy l]diphenyl- (9CI) (CA INDEX NAME)

L8 ANSWER 6 OF 7 CAPLUS COPYRIGHT 2007 ACS on STN

ACCESSION NUMBER: 1991:681283 CAPLUS

DOCUMENT NUMBER: 115:281283

TITLE: Manufacture of metal-coordinating organic silicon

polymers

INVENTOR(S): Sakata, Kanji; Okizaki, Akio; Kunitake, Toyoki PATENT ASSIGNEE(S): Research Development Corp. of Japan, Japan

SOURCE: Jpn. Kokai Tokkyo Koho, 6 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent Japanese

LANGUAGE:
FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 03170529	A	19910724	JP 1989-309926	19891129
JP 2795379	B2	19980910		•

PRIORITY APPLN. INFO.: JP 1989-309926

19891129

AB Title polymers useful for absorption, separation, and concentration of metal ions are

manufactured by coordinating R1nR2mSi(OR)4-n-m (R1 = organic group containing metal

ion coordinatable group; R2 = organic group without metal ion coordinatable group; m = 0-2; n = 1-3) with metal ions, hydrolyzing and polycondensing the resulting metal ion-coordinated alkoxysilanes, and removing the metal ions. Thus, 10 parts NH2(CH2)3SiOMe3 (I) was treated with 35 parts CuCl2 in MeOH, polymerized in the presence of NH4OH at 150° for 3 h, and immersed in 1N HCl to give white polymer which showed Cu absorption 20% in 1% CuCl2 for 24 h, vs. <0.01 when I was hydrolytically polymerized without CuCl2.

IT 18586-39-5DP, 2-(Diphenylphosphino)ethyltriethoxysilane, metal complexes

RL: PREP (Preparation)

(manufacture and hydrolytic polymerization)

RN 18586-39-5 CAPLUS

CN Phosphine, diphenyl[2-(triethoxysilyl)ethyl]- (CA INDEX NAME)

$$\begin{array}{c} \text{OEt} \\ | \\ \text{EtO-} \sin \text{CH}_2 - \cos \text{CH}_2 - \text{PPh}_2 \\ | \\ \text{OEt} \end{array}$$

L8 ANSWER 7 OF 7 CAPLUS COPYRIGHT 2007 ACS on STN

ACCESSION NUMBER:

1985:406483 CAPLUS

DOCUMENT NUMBER:

103:6483

TITLE:

Gas chromatographic study on interactions of olefins with chemically bonded transition metal complexes

AUTHOR(S):

Wasiak, Wieslaw

CORPORATE SOURCE:

Wydzial Chem., Uniw. A. Mickiewicza, Poznan, 60-780,

Pol.

SOURCE:

Chemia Analityczna (Warsaw, Poland) (1984), 29(2),

211-20

CODEN: CANWAJ; ISSN: 0009-2223

DOCUMENT TYPE:

Journal

LANGUAGE:

English

The packings Si:Si(OEt)(CH2)2PPh2.MCl2 (M = Ni, Cu) were prepared from the reaction of SiOH groups on silica surface with (EtO)3Si(CH2)2PPh2 and MCl2; the complex is able to bind an addnl. ligand e.g., olefins.

Lability of such complexes is a condition for chromatog. separation of alkenes. The columns packed with the bonded diphenylphosphine complexes were used for gas-chromatog. separation of mixts. of alkanes and alkenes, styrene derivs. ketones, and chloroalkanes.

IT 18586-39-5

RN 18586-39-5 CAPLUS

CN Phosphine, diphenyl[2-(triethoxysilyl)ethyl]- (CA INDEX NAME)

$$\begin{array}{c} \text{OEt} \\ \mid \\ \text{EtO-Si-CH}_2\text{-CH}_2\text{-PPh}_2 \\ \mid \\ \text{OEt} \end{array}$$